# 1-Bit Dual-Supply Non-Inverting Level Translator

The NLSV1T34 is a 1-bit configurable dual-supply voltage level translator. The input  $A_n$  and output  $B_n$  ports are designed to track two different power supply rails,  $V_{CCA}$  and  $V_{CCB}$  respectively. Both supply rails are configurable from 0.9 V to 4.5 V allowing universal low-voltage translation from the input  $A_n$  to the output  $B_n$  port.

### **Features**

- Wide V<sub>CCA</sub> and V<sub>CCB</sub> Operating Range: 0.9 V to 4.5 V
- High-Speed w/ Balanced Propagation Delay
- Inputs and Outputs have OVT Protection to 4.5 V
- Non-preferential V<sub>CCA</sub> and V<sub>CCB</sub> Sequencing
- Power-Off Protection
- Ultra-Small Packaging: 1.45 mm x 1.0 mm ULLGA6
- This is a Pb-Free Device

## **Typical Applications**

• Mobile Phones, PDAs, Other Portable Devices

### **Important Information**

• ESD Protection for All Pins: HBM (Human Body Model) > 3000 V

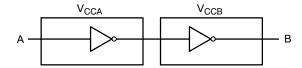


Figure 1. Logic Diagram



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ULLGA6 MU SUFFIX CASE 613AF MARKING DIAGRAM

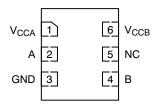
QM

Q = Specific Device Code

M = Date Code

= Pb-Free Package

### **PIN ASSIGNMENT**



(Top View)

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLSV1T34AMX1TCG	ULLGA6 (Pb-Free)	

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

### **PIN ASSIGNMENT**

PIN	FUNCTION
V <sub>CCA</sub>	Input Port DC Power Supply
V <sub>CCB</sub>	Output Port DC Power Supply
GND	Ground
Α	Input Port
В	Output Port

### **TRUTH TABLE**

INPUTS	OUTPUTS
Α	В
L	L
Н	Н

### **MAXIMUM RATINGS**

Symbol	Rating		Value	Condition	Unit
V <sub>CCA</sub> , V <sub>CCB</sub>	DC Supply Voltage		-0.5 to +5.5		V
V <sub>I</sub>	DC Input Voltage	Α	-0.5 to +5.5		V
V <sub>O</sub>	DC Output Voltage (Power Down)	В	-0.5 to +5.5	V <sub>CCA</sub> = V <sub>CCB</sub> = 0	V
	(Active Mode)	В	-0.5 to +5.5		V
I <sub>IK</sub>	DC Input Diode Current		-20	V <sub>I</sub> < GND	mA
I <sub>OK</sub>	DC Output Diode Current		-50	V <sub>O</sub> < GND	mA
Io	DC Output Source/Sink Current		±50		mA
I <sub>CCA</sub> , I <sub>CCB</sub>	DC Supply Current Per Supply Pin	±100		mA	
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100		mA	
T <sub>STG</sub>	Storage Temperature		-65 to +150		°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

## **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter	Min	Max	Unit	
V <sub>CCA</sub> , V <sub>CCB</sub>	Positive DC Supply Voltage	0.9	4.5	V	
V <sub>I</sub>	Bus Input Voltage	GND	4.5	V	
V <sub>IO</sub>	Bus Output Voltage (Power Down Mode)	В	GND	4.5	V
	(Active Mode)	В	GND	V <sub>CCB</sub>	V
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
Δt / ΔV	Input Transition Rise or Rate $V_{l}$ , from 30% to 70% of $V_{CC}$ ; $V_{CC}$ = 3.3 V ±0.3 V	0	10	nS	

# DC ELECTRICAL CHARACTERISTICS

					-40°C to	o +85°C	
Symbol	Parameter	Test Conditions	V <sub>CCA</sub> (V)	V <sub>CCB</sub> (V)	Min	Max	Unit
V <sub>IH</sub>	Input HIGH Voltage		3.6 – 4.5	0.9 – 4.5	2.2	-	V
			2.7 – 3.6	1	2.0	-	
			2.3 – 2.7	1	1.6	-	
			1.4 - 2.3	1	0.65 * V <sub>CCA</sub>	-	
			0.9 – 1.4	1	0.9 * V <sub>CCA</sub>	-	1
V <sub>IL</sub>	Input LOW Voltage		3.6 – 4.5	0.9 – 4.5	-	0.8	V
			2.7 – 3.6	1	-	0.8	1
			2.3 – 2.7	1	-	0.7	1
			1.4 - 2.3	1	-	0.35 * V <sub>CCA</sub>	
			0.9 – 1.4	1	-	0.1 * V <sub>CCA</sub>	1
V <sub>OH</sub>	Output HIGH Voltage	$I_{OH} = -100 \mu A; V_I = V_{IH}$	0.9 - 4.5	0.9 – 4.5	V <sub>CCB</sub> - 0.2	-	V
		$I_{OH} = -0.5 \text{ mA}; V_I = V_{IH}$	0.9	0.9	0.75 * V <sub>CCB</sub>	-	1
		$I_{OH} = -2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	1.05	-	1
		$I_{OH} = -6 \text{ mA}; V_I = V_{IH}$	1.65	1.65	1.25	-	1
			2.3	2.3	2.0	-	1
		$I_{OH} = -12 \text{ mA}; V_I = V_{IH}$	2.3	2.3	1.8	-	1
			2.7	2.7	2.2	-	
		$I_{OH} = -18 \text{ mA}; V_I = V_{IH}$	2.3	2.3	1.7	-	
			3.0	3.0	2.4	-	
		$I_{OH} = -24 \text{ mA}; V_I = V_{IH}$	3.0	3.0	2.2	-	1
V <sub>OL</sub>	Output LOW Voltage	$I_{OL} = 100 \mu A; V_I = V_{IL}$	0.9 – 4.5	0.9 – 4.5	-	0.2	V
		$I_{OL}$ = 0.5 mA; $V_I$ = $V_{IH}$	1.1	1.1	-	0.3	1
		$I_{OL} = 2 \text{ mA}; V_I = V_{IH}$	1.4	1.4	-	0.35	
		$I_{OL} = 6 \text{ mA}; V_I = V_{IL}$	1.65	1.65	-	0.3	
		$I_{OL}$ = 12 mA; $V_I$ = $V_{IL}$	2.3	2.3	-	0.4	
			2.7	2.7	-	0.4	1
		$I_{OL}$ = 18 mA; $V_I$ = $V_{IL}$	2.3	2.3	-	0.6	
			3.0	3.0	-	0.4	1
		$I_{OL}$ = 24 mA; $V_I$ = $V_{IL}$	3.0	3.0	-	0.55	1
lį	Input Leakage Current	V <sub>I</sub> = V <sub>CCA</sub> or GND	0.9 - 4.5	0.9 – 4.5	-1.0	1.0	μΑ
I <sub>CCA</sub>	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$ , $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 - 4.5	-	2.0	μΑ
Іссв	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$ , $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 - 4.5	-	2.0	μА
CCA + ICCB	Quiescent Supply Current	$V_I = V_{CCA}$ or GND; $I_O = 0$ , $V_{CCA} = V_{CCB}$	0.9 – 4.5	0.9 – 4.5	-	4.0	μΑ
I <sub>OFF</sub>	Power OFF Leakage Current	V <sub>I</sub> = 4.5 V	0	0	-	5.0	μΑ

## TOTAL STATIC POWER CONSUMPTION (I<sub>CCA</sub> + I<sub>CCB</sub>)

	-40°C to +85°C										
	V <sub>CCB</sub> (V)										
	4.5 3.3			2.8 1.8			0.9				
V <sub>CCA</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
4.5		2		2		2		2		< 1.5	μΑ
3.3		2		2		2		2		< 1.5	μΑ
2.8		< 2		< 1		< 1		< 0.5		< 0.5	μΑ
1.8		< 1		< 1		< 0.5		< 0.5		< 0.5	μΑ
0.9		< 0.5		< 0.5		< 0.5		< 0.5		< 0.5	μА

NOTE: Connect ground before applying supply voltage V<sub>CCA</sub> or V<sub>CCB</sub>. This device is designed with the feature that the power-up sequence of  $V_{CCA}$  and  $V_{CCB}$  will not damage the IC.

### **AC ELECTRICAL CHARACTERISTICS**

			-40°C to +85°C										
							V <sub>CCI</sub>	<sub>B</sub> (V)					
			4.5 3.3 2.8 1.8 1.2			.2							
Symbol	Parameter	V <sub>CCA</sub> (V)	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t <sub>PLH</sub> ,	Propagation	4.5		1.6		1.8		2.0		2.1		2.3	nS
t <sub>PHL</sub> (Note 1)	Delay,	3.3		1.7		1.9		2.1		2.3		2.6	
(NOIC 1)	A to B	2.8		1.9		2.1		2.3		2.5		2.8	
		1.8		2.1		2.4		2.5		2.7		3.0	
		1.2		2.4		2.7		2.8		3.0		3.3	

<sup>1.</sup> Propagation delays defined per Figure 2.

### **CAPACITANCE**

Symbol	Parameter	Test Conditions	Typ (Note 2)	Unit
C <sub>I/O</sub>	I/O Pin Input Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CCA/B}$	5.0	pF
C <sub>PD</sub>	Power Dissipation Capacitance	$V_{CCA} = V_{CCB} = 3.3 \text{ V}, V_{I} = 0 \text{ V or } V_{CCA}, f = 10 \text{ MHz}$	5.0	pF

Typical values are at T<sub>A</sub> = +25°C.
 C<sub>PD</sub> is defined as the value of the IC's equivalent capacitance from which the operating current can be calculated from: I<sub>CC(operating)</sub> ≅ C<sub>PD</sub> x V<sub>CC</sub> x f<sub>IN</sub> where I<sub>CC</sub> = I<sub>CCA</sub> + I<sub>CCB</sub>.

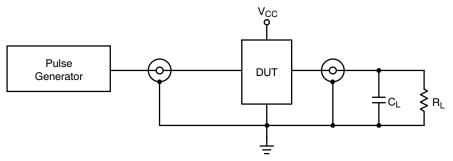
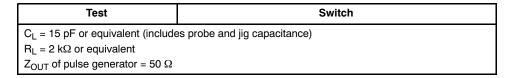
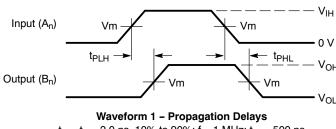


Figure 2. AC (Propagation Delay) Test Circuit





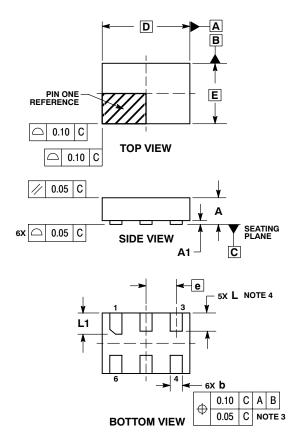
 $t_R$  =  $t_F$  = 2.0 ns, 10% to 90%; f = 1 MHz;  $t_W$  = 500 ns

Figure 3. AC (Propagation Delay) Test Circuit Waveforms

	V <sub>cc</sub>
Symbol	0.9 V – 4.5 V
V <sub>mA</sub>	V <sub>CCA</sub> /2
V <sub>mB</sub>	V <sub>CCB</sub> /2

### PACKAGE DIMENSIONS

ULLGA6 1.45x1.0, 0.5P CASE 613AF-01 **ISSUE A** 

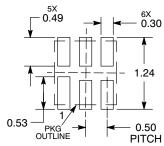


#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION b APPLIES TO PLATED TERMINAL
  AND IS MEASURED BETWEEN 0.15 AND
- 0.30 mm FROM THE TERMINAL TIP.
  A MAXIMUM OF 0.05 PULL BACK OF THE
  PLATED TERMINAL FROM THE EDGE OF THE PACKAGE IS ALLOWED.

	MILLIMETERS							
DIM	MIN	MAX						
Α		0.40						
A1	0.00	0.05						
b	0.15	0.25						
D	1.45	BSC						
E	1.00	BSC						
е	0.50	BSC						
L	0.25	0.35						
L1	0.30	0.40						

### **MOUNTING FOOTPRINT SOLDERMASK DEFINED\***



DIMENSIONS: MILLIMETERS

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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